Spin con gurations in circular and rectangular vertical quantum dots in a magnetic eld: Three-dim ensional self-consistent simulation

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The magnetic eld dependence of the electronic properties of real single vertical quantum dots in circular and rectangular mesas is investigated within a full three-dimensional multiscale selfconsistent approach without any a priori assumptions about the shape and strength of the connement potential. The calculated zero eld electron addition energies are in good agreement with available experimental data for both mesa geometries. Charging diagrams in a magnetic eld for number of electrons up to ve are also computed. Consistent with the experimental data, we found that the charging curves for the rectangular mesa dot in a magnetic eld are atter and exhibit less features than for a circular mesa dot. Evolution of the singlet-triplet energy separation in the two electron system for both dot geometries in magnetic eld was also investigated. In the limit of large eld, beyond the singlet-triplet transition, the singlet-triplet energy di erence continues to become m ore negative in a circular mesa dot without any saturation within the range of considered magnetic elds whilst it is predicted to asymptotically approach zero for the rectangular mesa dot. This different behavior is attributed to the symmetry "breaking" that occurs in the singlet wave-functions in the rectangular mesa dot but not in the circular one.

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I. IN TRODUCTION

In recent years the electronic properties of sem iconductor quantum dots (QDs) have attracted considerable attention because these zero-dimensional objects exhibit properties characteristic of atom ic few electron systems. QDs are also regarded as promising candidates for future device applications [1], not least of which is the possibility of realizing a scalable quantum computer [2]. A considerable amount of theoretical and experimental research has been devoted to understanding the electronic properties of cylindricalm esa structures within which the QD has a shape of a thin disc. These disc-shaped QDs are usually form ed from double barrier structures made in to sm all mesas and surrounded by a gate electrode. The number of electrons is fully tunable starting from zero β]. In such systems three-dimensional quantization coupled with rotational symmetry leads to the existance of a "shell structure" in the electron addition energy, i.e. for certain electron numbers the electron addition energies show pronounced maxim a. Spin e ects also lead to the appearance of sm aller secondary peaks in the midshell regions, in accordance with Hund's rst rule [4].

In contrast to real atom s, electrons in vertical QDs occupy a sizable region of space of the order of 100 nm. This allow sutilization of a relatively sm alland readily accessible magnetic eld to probe their electronic structure

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and also to induce transitions between the various electronic states as the number of particles and the strength of eld are varied. However, perfect circular symmetry of the QD is di cult to achieve and maintain in real scalable electronic circuits. Ideal atom istic features are also very sensitive to any kind of disruption in the system [5]. This dictates the necessity of understanding the response of the electronic structure to various geometric deform ations.

C om pared with circular Q D s which have been studied by a variety of m ethods [4], QDs in rectangular m esas (hence forth called rectangular QDs for brevity) have attracted considerably less attention both experim entally and theoretically. Invariably, most calculations assume a pure two-dimensional con nement potential. Frequently [6, 8, 9, 10], a model two-dimensional anisotropic harmonic oscillator potential (1=2)m $(!_x^2 x^2 + !_y^2 y^2)$ characteristic of an elliptic QD with con nem ent strengths $!_x$ and $!_{v}$ in the x and y directions respectively, is used in theoretical calculations for this purpose. Simulations conducted with such a potential [6] showed that it is not straightforw ard to m atch the experim ental geom etric aspect ratio = L=S, where L(S) is the length of the longest (shortest) side of the top mesa contact, to the potential deform ation ratio = $!_v = !_x$. B reakdown of Hund's rst rule was also found in QDs with a deform ation ratio as small as 1.2 [6]. Evolution of the excitation spectra in circular and elliptic QDs in a magnetic eld up to 4 T was also studied [10]. W hilst the previous works gave some understanding and clari cation of the shell structure evolution in response to potential deform ations, the detailed analysis and com parison with experim ental data is still lacking.

In this work we try to remedy this shortcoming and present calculations of the zero eld addition energy spectra and charging diagram s in an applied m agnetic eld for real circular and rectangular vertical Q D m esa structures. We perform a full scale three-dimensional (3D) analysis of the QDs without any a priori assumptions about the shape or strength of the con nem ent potential. W e utilize density-function theory (DFT) to describe the many body interactions amongst the electrons in the QD, and employ a sem i-classicalThom as Ferm i approach to treat charge evolution outside the QD region. In this multiscale approach, the con nem ent potential is obtained directly from the self-consistent solution of the Poisson and Schrodinger (Kohn-Sham) equations with corresponding device boundary conditions. Our calculations are based on real experim ental structures for which well resolved addition energy spectra and magnetic eld characteristics have already been m easured [3, 6, 7]. P reviously this full scale method was applied to a variety of problems such as, e.g., the simulation of four-gated QD m esas with a square geom etry [11] which showed that elliptical deform ations have little e ect on the addition energy spectra but a ected the charge con guration greatly. Prelim inary calculations for rectangular QDs also showed that the shell structure is completely destroyed for > 12

and a W igner molecule in the two-electron system is formed for > 3 [12].

The paper is organized in the following way. The QD structures utilized in this work are brie y described in the next Section. A detailed description of our model is given in Section III. In Section IV we rst compare addition energy spectra and shell structures of the circular and rectangular QDs in the absence of a magnetic eld (Section IV A). Charging processes and evolution of spin states under application of magnetic eld are then considered in Section IV B. Comprarison with experimentally measured charging diagrams in a magnetic eld is also performed in the same section. The particularly interesting and in portant case of a two electron system is addressed in Section IV C. Finally, Section V contains concluding remarks.

II. DEVICE STRUCTURES

O ur Q D structures have a layered pro le in the vertical z-direction [3] which are the same for both the circular and rectangular mesa structures. Two layers of A $l_{0:22}$ G $a_{0:78}$ A s are used as potential barriers for electrons con ned in a quantum wellm ade of $In_{0:05}$ G $a_{0:95}$ A s. C onnem ent of electrons in the lateral xy-plane is achieved by applying a bias $V_{\rm G}$ to the gate on the side of the mesa. Full details on the geom etry, layer com position of these structure, and the measurem ent techniques can be found elsewhere [3, 6, 7, 16].

For the sinulations described below, we represent the m esa and substrate as a cylinder or a rectangle with total height of 350 nm. The side gate width is taken to be equal to 150 nm, while the center of the quantum well is located 116.5 nm from the top of the side gate. The low er 100 nm of the simulation cylinder is assumed to be buried in the substrate. The diam eter of a circularm esa is equal to 0.5 m in accordance with experimentally measured m esa [3]. For the rectangular QD m esas, L and S are taken to be 0.55 m and 0.4 m (= 1.375), and 0.65 m and 0.45 m (= 1.44). These m esas correspond respectively to structures identie et as rectangular QD X and rectangular QD Y studied earlier at low m agnetic elds [6]. A coordingly we refer to them as rectangular QD X and rectangular QD Y in this paper.

III. MODEL AND SIMULATION DETAILS

W ithin the spin-density functional theory, which we use to describe electrons con ned in the QD region, the charge density is calculated after solving separate singleparticle K ohn-Sham equations for electrons with spin up (") and down (#):

$$\hat{H}^{(\#)}(\pi) = \pi^{(\#)}(\pi) = \pi^{(\#)}(\pi); \quad (1)$$

where the H am iltonian $\hat{H}^{(\#)}$ is given as follows:

$$\hat{H}^{"(\#)} = \hat{T} + (r) + E_{c}(r) + v_{xc}^{"(\#)}(r)$$
: (2)

In this equation \hat{T} is the kinetic energy operator which in the presence of an external magnetic eld B reads as:

$$\hat{T} = \frac{1}{2}$$
 i~r + $\frac{e}{c}A$ $\frac{1}{m(r)}$ i~r + $\frac{e}{c}A$; (3)

where m (r) is the position dependent electron e ective m ass, and A = (1=2) (B y; B x) is the corresponding vector potential. We assume here that the magnetic eld is oriented along the z-direction and neglect Zeem an splitting for clarity.

In Eq. (2), E $_{\rm c}$ (r) stands for the conduction band o – set between the di erent materials. The values of E $_{\rm c}$ (r) are xed at 180 and -40 m eV for A $l_{0.22}$ G $a_{0.78}$ A s/G aAs and $In_{0.05}$ G $a_{0.95}$ A s/G aAs respectively. Note that for the real structures with non-zero doping in the G aAs contact regions, the value of E $_{\rm c}$ (r) for $In_{0.05}$ G $a_{0.95}$ A s/G aAs is di cult to determ ine precisely.

The exchange-correlation potential $v_{xc}^{"(\#)}(r)$ is computed within the local spin density approximation (LSDA) [13]. Note that this functional does not explicitly depend on magnetic eld. Comparison of DFT results with calculations using current-spin density functional theory [14] for two-dimensional systems showed that this approximation is reliable over a wide range of magnetic eld, although at higher elds, e ects of paramagnetic currents in $v_{xc}^{"(\#)}(r)$ become more important.

The potential $(r) = _{ext}(r) + _{ion}(r) + _{H}(r)$ in Eq. (2) is the sum of the external potential $_{ext}(r)$ due to the applied voltage, screening potential $_{ion}(r)$ arising from the ionized impurities in the structure, and H artree potential $_{H}(r)$ accounting for the repulsive electron-electron interactions. It is obtained from the solution of the Poisson equation:

$$r(r)r(r) = 4(r);$$
 (4)

where (r) is the dielectric constant of the m edium, and (r) is the charge density which inside the QD region is equal to

(r) = e
$$\begin{array}{c} X \\ \text{occup} \end{array}$$
 (r) $\begin{array}{c} 2 \\ + \end{array}$ (r) $\begin{array}{c} 2 \\ \# \\ \end{array}$ (r) $\begin{array}{c} 2 \\ \# \\ \end{array}$ (r) (5)

with the sum mations spanning occupied states for electrons with spin up and down (the number of those states is, in general, di erent). Outside the region, charge distribution is determined from electron n (r) and hole p(r) densities calculated within the semi-classical Thom as Fermi approximation [15, 16] screened by the ionized donors and acceptors with concentrations $N_{\rm D}^+$ (r) and $N_{\rm A}$ (r) (which were assigned their nom inal values [3, 6, 7]):

$$(r) = e N_{D}^{+}(r) N_{A}(r) + p(r) n(r)$$
: (6)

Since vertical QDs are usually much smaller than the physical dim ensions of the device, the Kohn-Sham wavefunctions actually vanish long before reaching the device boundaries. This allow sus to embed a local region in the globalmesh for solving the Kohn-Sham equations. This local region is chosen to be large enough to ensure vanishing wavefunctions on its boundaries. For the Poisson equation (4), zero norm al electric eld on the lower part of the simulated structure buried in the substrate and on the top contact region are used as a boundary condition. On other surfaces, not covered by the side gate, the potential is set equal to the Schottky barrier value $V_{\rm S} = 0.9 \, \text{eV}$. Boundary values of the potential on the side gate are equal to the Schottky barrier value m odied by the applied gate bias, $V_S = V_G$. The system of Kohn-Sham and Poisson equations (1), (4) is solved iteratively until a self-consistent solution for the K ohn-Sham orbitals "(#) (r) and eigenvalues ""(#) is obtained.

The calculations are performed on a parallel platform by means of the nite element method (FEM) with trilinear polynomials on a variable size grid [17]. Previously FEM was applied in electronic structure calculations [18]. The advantages of FEM utilization are the ability to system atically in prove the accuracy by expanding the basis set and its perfect suitability for parallelization.

In our approach Poisson's equation is solved by means of the dam ped New ton-Raphson method while the generalized eigenvalue problem obtained after discretization of the Kohn-Sham equation is tackled by means of a subspace iteration method based on a simple Rayleigh-Ritz analysis [17]. The small number of required eigenpairs (in the present work, less than 10) made this approach su cient. A parallel con jugate-gradient m ethod preconditioned with block Jacobiwith an incomplete LU factorization on the blocks available in PETSc (Portable, Extensible Toolkit for Scientic Computation) [19] is utilized for solving the resulting matrix equations. In the presence of a magnetic eld, the matrix obtained from the Kohn-Sham equation is Herm it ian and the herm it ianconjugate method [19] with the same preconditioner as above had to be used in solving the eigenvalue problem . Compared to the ordinary conjugate gradient method with a Jacobi preconditioner, we found that this approach gives rise to at least an order of magnitude increase in perform ance especially when dealing with Hermitian matrices [20].

A fter the eigenvalues are determ ined, the electron charging diagram can be calculated. The experimentally measured charging diagram is obtained by single electron transport spectroscopy [3, 6, 7], when the QD is in the regime of C oulom b blockade with only a very small bias applied across the QD in the vertical z-direction. C onsequently, the di erence between the chemical potentials of the source and drain contacts is negligible and both of them can be set to zero without loss of generality. A charging event occurs when the chemical potential of the QD becomes equal to that of the source (or drain) contact. Then we can determ ine the stable electronic congeneration is a set of the source (or drain) contact.

uration by directly comparing the total energy E (N) of the N -electron system with the system containing N 1 electrons, the di erence of which gives the required value of the chemical potential (N). Furthermore, we use Slater's rule [21, 22] (transition state technique) in order to calculate (N):

$$(N) = E(N) E(N 1) "(N 1=2);$$
 (7)

where "(N 1=2) is the eigenvalue of the state with half occupancy in the system with N 1=2 electrons (the transition state). If (N) < 0, then the N electron conguration is stable, otherwise the number of electrons in the QD is N 1. The voltage V_G (N) at which (N) = 0 gives the charging voltage for the N -th electron (or equivalently it de nes the boundary between stable con gurations with N and N 1 electrons).

A smentioned in Section I, an external magnetic eld can induce changes in the spin con guration even when the number of electrons con ned in the QD remains constant. Slater's nule can be used only when there is a change in occupancy of one eigenlevel. If a change in the number of electrons is accompanied by spin rotations (that is, the occupancy of several levels is changed at the same time), it becomes necessary to use several transition states sequentially (this increases the am ount of computations but does not invalidate Slater's nule). How ever, the number of such situations is small so that the overall application of Slater's rule signi cantly decreases the am ount of computational time required to calculate the full charging diagram in magnetic elds [27].

Having obtained (N), we can determ ine the electron addition energy by $rst \ computing \ the so-called \ capacitive energy [23]:$

$$_{2}(N) = (N) (N 1):$$
 (8)

W e evaluate this quantity at the bias V_G (N) corresponding to the addition of the N-th electron to the system so that $_2$ (N) = (N 1). Together with the charging voltage V_G (N), it is this quantity which is analyzed in detail in the following Section. Note also that this de nition of the addition energy is consistent with other calculations where a rigid external potential is used to create electron con nem ent [4, 6, 8, 10, 11].

IV. RESULTSAND DISCUSSION

A. Addition energy spectra at zero m agnetic eld

We rst consider the addition energy spectra of the circular and rectangular QDs in the absence of a magnetic eld. The calculated spectra are shown in Fig. 1 together with the corresponding experimental spectra taken from Ref. 6. The spectrum of the QD in the circular mesa (Fig. 1, lower part) has been discussed in great detail earlier [6] so here we just brie y review it. It exhibits pronounced maxim a for two and six electrons due to the

rst and second shell closures characteristic of Q D s with parabolic 2D circular con nem ent. The peaks and valleys are a consequence of the interplay between con nement and many-body e ects. For two electrons in the QD, the lowest single-particle state $"_1$ is fully occupied. The third electron populates the next available eigenstate with $"_2 > "_1$, thus making addition of the electron much m ore energetically costly than for the case of the second electron. The same situation is repeated for N = 6 when the second shell is complete. A smaller peak at N = 4 is due to the ful llm ent of H und's rst rule. The total spin S of the N -electron system is equal to zero (singlet) for N = 2 and 6 and to one (triplet) for N = 4. The agreem ent between the calculated and experim ental spectra is very good, for both peaks and valleys. From the energy separation between the two lowest adjacent eigenvalues we can deduce that the con nem ent strength $\sim!$ in the emptyQD is about 6 m eV.

The analysis for the rectangular QD spectra is more challenging. From a simple model of a 2D anisotropic harm onic oscillator with eigenenergies $"_{n_x,n_y} = ~!_x (n_x + 1=2) + ~!_y (n_y + 1=2)$, with quantum numbers n_x ; $n_y = 0$; 1; :::, one can see that in general, except at certain special deform ations, there are no degeneracies in the eigenspectrum at 0 T [6]. This means that the shell structure of a circularQD with strong maxim a for 2, 6, 12, ... electrons in the addition energy spectra will not hold here, and one should expect maxim a for most even electronnum bers. This simple interpretation is largely con med by our calculations.

Experimentally, because of side wall etching, the sizes of the fabricated mesas can be determined only with about 5 % accuracy [6]. To assess the e ect of this uncertainty for the rectangularQDs, we rst performed calculations of the addition spectra for three systems with geometrical aspect ratios equal and 5 % of the value given for rectangularQD X: namely = 1:306, 1:375 and 1:444. Note that the last structure has an aspect ratio that is very close to the nominal value = 1:44 for rectangularQD Y [6]. Hence, we compare our calculated spectra to spectra for both rectangularQD s X and Y. The results are also given in Fig. 1, middle and upper part respectively. Surprisingly our calculations for

= 1:444 are in excellent agreem ent with the experim ental data for rectangular QD Y, whilst none of the 5 % variation-spectra are able to describe the experim ental results as well for rectangular QD X, although the calculated spectrum for the structure with = 1:444 is closest to that m easured. In fact, the experim ental addition spectrum for X is sim ilar in some respects to the one for the circular QD indicating that this structure m ay have an e ective aspect ratio m uch low er than can be assum ed on the basis of its geom etrical aspect ratio alone. This conclusion is also corroborated by examining the m agnetic eld dependence of the charging digram s for these structures (see Section IV B).

Further inspection of the calculated spectra reveals that the di erence (contrast) between the peaks and valleys for the rectangular QDs is much lower than for the circular QD. We also note that the peak for N = 2 is signi cantly suppressed, and a 10 % di erence in gives rise to the N = 6 feature changing from a minima to a maxima (increasing from 1.306 to 1.444). This shows that the electronic structure in rectangular QDs is very sensitive to even small distortions of the con nem ent potential and the precise balance between all contributions to the total energy is essential for its accurate description. On the other hand, the four electron peak appears to be robust and is present in all the calculated addition energy spectra. This is because there is a trivial shell cb-sure at N = 4 since there is now no degeneracy between the second and third low est single-particle eigenvalues as is the case for the circular QD.

In order to better understand the electronic properties of a rectangular QD, we plot the wave-functions for the four lowest eigenvalues for the case of an empty QD at 1:6 and 1:3 V, and also for the QD contain- $V_G =$ ing six electrons at $V_G = 1.3 V$ (Fig. 2). One can see that the "spread" of the wave-functions progressively increases from (a) to (c) not only because the presence of electrons in the QD induces a repulsive C oulom b potentialwhich e ectively " attens" the bottom of the conduction band, but also this e ect occurs in the empty QD by solely varying the gate bias. This is a consequence of the three-dim ensionality of the mesa structure, which cannot be reproduced in model 2D calculations with a rigid connem ent potential. The doped regions just above and below the QD are never fully depleted, and changes in the gate bias a ect the charge distribution in them as well. The resulting changes in the potential are carried over into the QD and lead to the e ective decrease of the con nem ent strength as the gate bias becom es m ore positive. The same e ect is also present in circular QDs [11]. It can be seen that the con nem ent decreases with increasing gate bias and the population in the QD.At the same time, the potential deform ation ratio also increases, i.e. the QD becom es m ore elongated. This is a manifestation of a self-consistent e ect due to which electrons tend to localize as far as possible from each other in order to m in im ize the C oulom b repulsion. This results in a more e ective decrease of the con nement along the x-direction than the y-direction.

B. Charging diagram s in a magnetic eld

In Fig. 3 we plot the calculated charging voltage for N = 1 to N = 5 electrons as a function of magnetic eld (charging diagram) for the circular QD. Again these results have already been extensively discussed elsewhere [4,24] but they are used here to compare the properties of circular and rectangular QD s. Comparison with experiment for the circular QD [7] shows that overall agreement is very good, albeit the con nement potential at zero eld in ourm odel structure is som ew hat weaker, i.e., the curves are more closely spaced. The charging volt-

ages generally (in the considered range) increase with magnetic eld since the e ective con nem ent becom es stronger. The curves corresponding to the charging of 2 electrons exhibit "cusps" corresponding to vari-Ν ous magnetic eld induced spin and angularm om entum transitions. For the N = 3 charging curve arising from the addition of the third electron to the two-electron system, the cusp near 5 T (depicted by a square) is due to a change in the ground state con guration of the twoelectron system at B 5:6 T (the singlet-triplet transition) which a ects the addition energy of the third electron. The shift from 5.6 T to 5.0 T is due to a screening e ect and is consistent with the experim ent [7]. The cusp near 6 T (triangle) re ects an increase in the total spin of the three-electron system from S = 1=2 to S = 3=2, namely below this point two electrons are spin-up and one is spin-down while above this point all three electrons in the QD are spin-up and form a spin-polarized system. The dashed line in the 4 to 7 T region shows an excited state where three electrons have a total angularmomentum L = 2 but total spin S = 1=2. In our calculations this state never becom es the ground state, which is di erent from recent results based on the con guration interaction m ethod [24] where it was found that the transition from the ground state (L = 1, S = 1=2) to this state (L = 2, S = 1=2) was responsible for the lower eld cusp. However, the predicted di erence in the charging voltages is so sm all that given the large num ber of experim ental param eters (such as dopant distribution, geom etrical size of the structure, conduction band o sets, etc.) whose values cannot possibly be determined precisely, the real cause for this feature is di cult to ascertain at best.

In general, the rightmost cusp in the Fig. 3 charging diagram always corresponds to complete spin polarization of the electron system. The magnetic eld at which the form ation of this state occurs increases with the num ber of electrons since a stronger eld is required to overcom e the large kinetic energy accompanying single occupancy of consecutive orbitals. Cusps in the N -electron curves in the vicinity of B = 5 T are either due to changes in the 1)-electron con guration or due to single spin ro-(N tations in the N -electron system . The two cusps around 0.25 T in the N = 4 and N = 5 curves m ark the В breakdown of Hund's rst rule lling in the four-electron system and respective change in the addition energy of the fth electron due to the decrease of exchange energy in the four electron system, sim ilar to the N = 3 curve. 1:5 T in the N = 5 curve can be un-The cusp at B derstood in terms of the Fock-Darw in spectrum describing non-interacting particles [4]. A round that point, an electron undergoes a transition in the quantum numbers moving from the Fock-D arw in state with (n; l) = (0; 1)to (n; 1) = (0; 2), thereby increasing the total angularm omentum of the system while keeping the total spin value constant.

The calculated charging diagram of the rectangular QD with = 1:444 shown in Fig. 4 super cially looks

sim ilar to that of the circular QD. However, all cusps are less pronounced and the separation between consecutive curves is generally sm aller. The form er is due to the absence of a clear shell structure while the latter nds its origin in the decreased separation between the lower eigenlevels arising from the weaker con nement in the x-direction. We also observe that the magnetic elds at which transitions occur are approximately the same as in the circular QD (compare with Fig. 3). This can be explained by noticing that the QD surface area and the resulting electron density in both QD s are approximately equal. Since in the DFT the electron density determ ines the magnitude of the C oulom b and exchange interactions, it takes roughly the sam e am ount of energy in the two Q D systems to change these interactions in order to induce single electron transitions. The charging curvesm ove upward slightly faster with magnetic eld than those in Fig. 3. The reason for this behavior is again, com pared to the m agnetic con nem ent $!_c = eB = mc$, a sm aller value of $\sim!_x$ so that the magnetic eld a ects the related energy levels m ore strongly. Note that for the rectangular QD the N = 4 curve corresponds, at zero eld, to the charging of the fourth electron to form a singlet S = 0 state (two electrons with spin-up, two with spin-down), and this behavior is clearly di erent from that for the circularQD where four electrons obey Hund's rst rule close to zero magnetic eld. The singlet state continues to be the ground state up to B 5 T where the S = 1 state(shown by a dashed curve) brie y takes over.

At low magnetic elds (but above B 0.25 T), the calculated charging voltages for both N = 3 and N = 4 in the circular QD (Fig. 3) clearly decrease whilst the corresponding curves for the rectangular QD are initially " at" before moving upward (Fig. 4). This is due to the di erent response of the second lowest single-particle state to the magnetic eld. For a circular potential it rst decreases and then increases with magnetic eld, whilst a su ciently large potential deform ation results in the monotonic increase of this eigenvalue with magnetic eld. This is what happens in our modelled structure where

& 2 (see Fig. 2). At sm all magnetic elds the experimental charging diagram for rectangular QD X [see Fig. 5 (a)] actually looks very sim ilar to both the experim ental and calculated diagram s for a circularQD (see R ef. 7 and Fig. 3 respectively), although notably the cusps related to Hund's rst rule lling for N = 4 are absent near 0 T. This indicates that the elective aspect ratio characterizing the con nem ent potential in rectangular QD X is much closer to one than could be deduced from its geom etrical aspect ratio . On the other hand, the measured charging diagram for rectangularQDY [Fig. 5(b)] is closer in appearance to the calculated diagram for the rectangular QD shown in Fig. 4. In particular, curves for N = 3 and N = 4 m ove gradually upwards, whilst the curve for N = 5 m oves only slightly dow nw ards. The experim ental charging spectra for both circular and rectangular Q D s nonetheless reveal a weaker dependence of the charging voltages on the magnetic eld and a larger

separation between consecutive curves (within 30%) not observed in the theoretical spectra [28]. Both these discrepancies may be explained if the con nem ent is indeed stronger (in both x and y directions) in the experim ental devices, so that the magnetic eld is unable to perturb it appreciably.

C . Singlet-triplet transition in a two electron $${\rm system}$$

O ne of the m ost striking di erences between the calculated charging behavior of the QDs in the circular and rectangular m esa structures (Figs. 3 and 4) is found in the two electron system. The dashed curves for N = 2in both plots represent excited states. At low m agnetic elds, below the cusp on the charging curve, the excited state is a triplet (S = 1) whilst at high m agnetic elds, above the cusp, it is a singlet (S = 0). This cusp in fact m arks the singlet-triplet (S-T) transition. From the full and dashed curves in Figs. 3 and 4, we can extract (see Eqs. 7 and 8) the energy separation between the singlet and triplet states, nam ely

$$J = E^{T}(2) \quad E^{S}(2) = \frac{T}{2}(2) \quad \frac{S}{2}(2); \quad (9)$$

where symbols T and S stand for triplet and singlet states respectively. This singlet-triplet energy di erence for a QD with two electrons is very interesting because of its potential in portance for quantum computation. To the best of our know ledge this is the rst calculation of this in portant characteristic in a realistic system taking into account the full 3D nature of the problem . Hitherto, the singlet-triplet separation has been considered in a realistic non-circularQD using 2D con nem entpotentials produced by the gate voltages only [25]. Our theoretical data for both circular and rectangular QD s as a function ofmagnetic eld are shown in Fig. 6.0 ne can see that in the range of investigated magnetic elds the behavior of J in the two structures is radically di erent. In the lim it of large m agnetic eld J! O for the rectangular m esa Q D [9], whilst it continues to become more negative without any saturation in the case of the circular QD. Also, the value of J for the rectangular Q D is about three times smaller than for the circular QD at zero magnetic eld.

In order to gain a better insight into the calculated behavior of J in a magnetic eld, we show in Figs. 7 and 8 respectively the eigenfunctions of the occupied singlet and triplet states in a rectangularQD with = 1:444. In Fig. 7 we see that at low elds both of the electrons in the singlet state occupy the same space in the QD, i.e., their wave-functions are identical, and they become everm ore localized at the center of the QD with increasing eld. How ever, above B 5.8 T the electrons start to localize in opposite regions of the QD along the x-direction inducing a symmetry "breaking" so that the wave-functions no longer have the spatial symmetry of the connement potential around itsm inimum at the center of the QD. This e ect appears similar to so-called W igner crystallization,

i.e., spatial separation of electrons, caused by the applied magnetic eld [4]. Further increase of the magnetic eld gives rise to further localization of the electrons. In the case of the triplet state (Fig. 8), there is no such radical reconstruction of the electron wave-functions. They just become m ore localized around the center of the QD. The symmetry breaking in the singlet state also results in a change of the total electron density. It attains two "hum ps" similar to the electron density in the triplet state. The reconstruction of the singlet electron density is responsible for the predicted evolution of the singlettriplet splitting at large magnetic elds. W hen the electron densities of both states become similar, exchange and Coulomb energies also have close values. Coupled with the fact that the single-particle energy separation decreases with increasing eld (the energy levels condense in to the lowest Landau band [4]), this results in a vanishing J. Interestingly, as can be seen from Figs. 7, the overlap between the electron wave-functions at B = 8T is still appreciable (and close in value to that one at B = 6 T), and yet J ! 0.

The symmetry breaking does not occur in a circular QD where the electron density of the singlet state retains the symmetry of the connement potential in the range of magnetic elds considered in this work. As a result, the exchange energy of the triplet state is always smaller than that of the singlet. Starting from zero eld, the decrease in the separation between the two lowest single-particle energies as the magnetic eld is increased leads to the triplet becoming the ground state at B 5:6 T, but the singlet-triplet energy di erence J does not exhibit any saturation behavior at higher eld.

The behavior of the calculated singlet-triplet separation for the circular QD is in good agreement with experim ental data obtained by excited state spectroscopy [7] which enables the observation of electron tunneling through both ground and excited states. A though there is extensive experim ental data for the circular QD, detailed excited state spectra for the vertical rectangular QDs are currently unavailable. Clearly in light of the predictions concerning the behavior of J, it would be interesting to perform such experiments in the future. At present, we can only identify the two-electron S-T transtion for both rectangular QDs in the charging diagrams of Fig. 5 which just show the evolution of the ground states. W e do, how ever, note that recently, cotunneling was utilized to extract the values of the singlettriplet energy sepration for two electrons in a lateral QD with a spatially elongated (approximately harm onic) connem ent potential [26] where it was found that with increasing magnetic eld, J changes sign and then saturates, consistent with our calculations.

V. CONCLUSION

In this work we studied the electronic properties of vertical quantum QDs in circular and rectangular m esas using a multiscale density-functional approach within the local spin density approximation. The QD was treated fully quantum mechanically and the surrounding regions were described by a semiclassical Thom as Fermi approximation. The calculations were done on a 3D mesh by means of a nite element method. Slater's rule (the transition state technique) was utilized to study charging of the QDs. With this approach, we were able to calculate the zero magnetic eld electron addition energy spectra in the QDs as well as study the electron charging diagram s in a magnetic eld.

We found that the zero eld addition energy spectrum and charging diagram (charging voltages as a function of magnetic eld) of a circular QD are in good agreement with available experimental results. For rectangular QDs, we found that a 5 % variation from the nominal aspect ratio can give rise to marked di erences in the addition energy spectra. On the basis of a comparison with experimental data in a magnetic eld for rectangular mesa structures (Rectangles X and Y in Ref. 6) with di erent aspect ratios, we conclude that rectangular QD X most likely has a smaller e ective aspect ratio than previously reported, whilst our calculated results are in good agreement with those obtained for the rectangular QD Y.

From the charging diagram s, we also extracted the calculated magnetic eld dependence of the singlet-triplet energy separation J for a two electron system. Up to the singlet-triplet transition, this quantity decreases with magnetic eld for both circular and rectangular QDs. However, beyond that transition, in the limit of a strong eld, J for the rectangular QD asymptotically approaches zero whilst it continues to become more negative in the case of the circular QD in the range of considered magnetic elds. A nalysis of electron wave-functions revealed that the behavior of the singlet-triplet energy separation in a rectangular QD can be attributed to the "breaking" of the symmetry of the singlet wave-functions.

A cknow ledgm ents

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[1] K K.Likharev, Proc. IEEE 87, 606 (1999).

^[2] D. Loss and D.P. D iV incenzo, Phys. Rev. A 57, 120 (1998).

^[3] S.Tanucha, D.G. Austing, T. Honda, R.J. van der Hage, and L.P. Kouwenhoven, Phys. Rev. Lett. 77, 3613 (1996).

^[4] SM.Reimann and M Manninen, Rev.Mod.Phys.74,

1283 (2002).

- [5] P. Matagne, J.P. Leburton, D.G. Austing, and S. Tanıcha, Phys. Rev. B 65, 085325 (2002).
- [6] D.G. Austing, S. Sasaki, S. Tarucha, S.M. Reimann, M.Koskinen, and M.Manninen, Phys. Rev. B 60, 11514 (1999).
- [7] L P.K ouwenhoven, T H.O osterkam p, M W S.D anoesastro, M. Eto, D G. Austing, T. Honda, and S. Tarucha, Science 278, 1788 (1997).
- [8] A.V.M adhav and T.Chakraborty, Phys.Rev.B 49,8163 (1994); S.Tanucha, T.Honda, D.G.Austing, Y.Tokura, K.Muraki, T.H.Oosterkamp, J.W. Janssen, and L.P. Kouwenhoven, Physica E 3, 112 (1998); T.Ezaki, Y. Sugim oto, N.Mori, and C.Ham aguchi, Sem icond. Sci. Technol.13, A1 (1998); K.Hirose, N.S.W ingreen, Phys. Rev.B 59, 4604 (1999); I.H.Lee, Y.H.Kim, and K.-H Ahn, J.Phys.: Condens. Matter 13, 1987 (2001); B. Szafran, F.M. Peeters, S.Bednarek, and J.Adam owski, Phys.Rev.B 69, 125344 (2004).
- [9] P.S.D rouvelis, P.Schm elcher, and F.K.D iakonos, Phys. Rev. B 69, 155312 (2004).
- [10] Y. Tokura, S. Sasaki, D.G. Austing, and S. Tanucha, Physica B 298, 260 (2001).
- [11] P.M atagne, and J.P.Leburton, Phys. Rev, B 65, 155311 (2002).
- [12] P.M atagne and J.P. Leburton, in Quantum Dots and Nanowires, Eds. S. Bandyopadhyay and H. S. Nalwa, ASP, California (2003).
- [13] J.P. Perdew and Y.W ang, Phys. Rev. B 45, 13244 (1992).
- [14] F. Ancilotto, D. G. Austing, M. Barranco, R. Mayol, K. Muraki, M. Pi, S. Sasaki, and S. Tarucha, Phys. Rev. B 67, 205311 (2003).
- [15] S M . Sze, P hysics of Sem iconductor D evices, 2nd Edition, W iley Interscience, 1981.
- [16] P.M atagne, and J.P.Leburton, Phys. Rev, B 65, 235323 (2002).

- [17] K.-J. Bathe, Finite Element Procedures in Engineering Analysis, Prentice-Hall, Inc., New Jersey, 1982.
- [18] S.R.W. hite, J.W. W ilkins, and M. P. Teter, Phys. Rev. B 39, 5819 (1989); J.E. Pask, B.M. Klein, C.-Y. Fong, and P.A. Sterne, ibid. 59, 12352 (1999).
- [19] S.Balay, K.Buschelman, V.Eijkhout, W.D.Gropp, D. Kaushik, M.G.Knepley, LC.McInnes, B.F.Smith and H.Zhang, PETSC Users Manual, ANL-95/11 - Revision 2.1.5, Argonne National Laboratory, 2004.
- [20] J. Fettig, D.V. M elnikov, N. Sobh, and J.P. Leburton (unpublished).
- [21] J.C. Slater, Adv. Quantum Chem. 6, 1 (1972).
- [22] L R C. Fonseca, J.L. Jim enez, J.P. Leburton, and R M. Martin, Phys. Rev. B 57, 4017 (1998).
- [23] I.H. Lee, K. H Ahn, Y. H. Kim, R M. Martin, and J.P. Leburton, Phys. Rev. B 60, 13720 (1999).
- [24] B.Szafran, S.Bednarek, and J.Adam owski, Phys. Rev. B 67, 115323 (2003).
- [25] J.Kyriakidis, M.Pioro-Ladriere, M.Ciorga, A.S.Sachrajda, and P.Hawrylak, Phys. Rev. B 66, 035320 (2002).
- [26] D M. Zum buhl, C M. M arcus, M P. Hanson, and A C. G ossard, Phys. Rev. Lett. 93, 256801 (2004).
- [27] O urprevious calculations [16] have established the validity of Slater's rule for the number of electrons N > 1. N evertheless, for completeness we apply Slater's rule to determ ine the charging point for the rst electron as well.
- [28] Surprisingly the smaller separation between the calculated curves does not a ect the addition energy spectra which are in good agreement with measured data (Section IV A). This is because the addition energy is de ned not only by the gate voltage di erence between consequitive charging points but rather by the slope of
 - (N; V_G) vs. V_G which in itself is a highly non-trivial function of the QD device parameters and electron num ber (for discussion, see, e.g., [16, 24] and references therein).

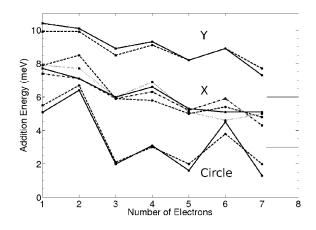


FIG.1: Addition energy spectra for the circular QD (lower part), the rectangular QD X (m iddle part), and the rectangular QD Y (upper part) at zero m agnetic eld. The parts are shifted by 3 m eV in the vertical direction for clarity. In all parts solid lines represent results of calculations, while dashed lines stand for experim ental data. D otted and dash-dotted lines for rectangular QD X are the results of calculations for structures with = 1:306 and 1:444 respectively. The calculated curve for the rectangular QD X are the same as the dash-dotted curve for the rectangular QD X.

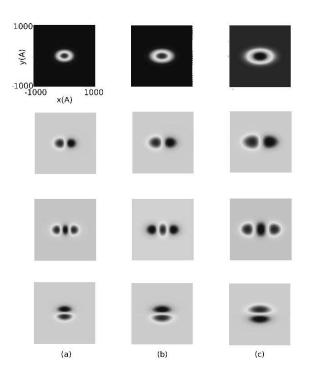


FIG.2: Two-dimensional contour plots of the wave-functions for the four lowest eigenvalues (from top to bottom) in the rectangularQD with = 1:444: (a) N = $0, V_G = 1:6 V$, (b) N = $0, V_G = 1:3 V$, (c) N = $6, V_G = 1:3 V$. Coordinate z is xed in the center of the QD.

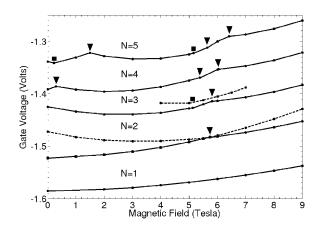


FIG.3: Calculated charging diagram (solid curves) for ground states in a magnetic eld for the circularQD. The dashed lines show some excited states. Triangles (H) de ne boundaries of regions with di erent total spin and angular momentum in the ground state of the N-electron system. Squares () show features in the ground state of the N-electron system due to reconstruction of the (N 1)-electron system.

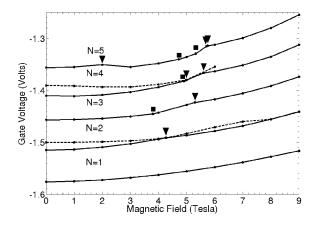


FIG.4:Same as in Fig.3 but for the rectangularQD with = 1:444. In this case triangles (H) de ne boundaries of regions with di erent total spin and (n_x, n_y) quantum numbers in the N -electron system.

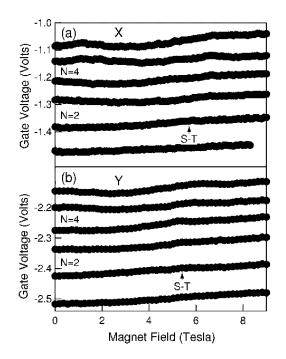


FIG. 5: Experimental charging diagrams showing ground state evolution with magnetic eld for (a) rectangular QD X, and (b) rectangular QD Y. The position of the N = 2 singlet-triplet (S-T) transition is marked.

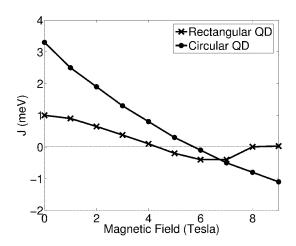


FIG.6: Calculated singlet-triplet energy separation J in the two-electron system as a function of the magnetic eld. = 1:444 for the rectangular QD.

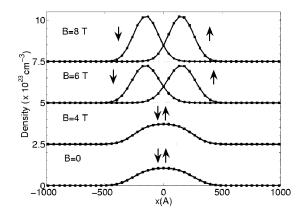


FIG. 7: Single-particle electron densities in the x-direction in the rectangular QD with = 1:444 for the singlet state at di erent magnetic elds (coordinates y and z are xed in the middle of the QD). A rrows (") and (#) correspond to the electrons with spin up and down. The data for B = 0, 4 T and 6, 8 T are obtained at V_G = 1:45 and 1:47 V respectively. The curves for di erent magnetic elds are shifted in the vertical direction by 2:5 10²³ cm³ for clarity.

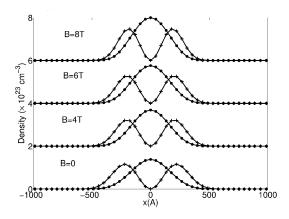


FIG.8: Same as in Fig. 7 but for the triplet state. Curves with circles () and pluses (+) are for the ground and rst excited occupied states respectively. The curves for di erent m agnetic elds are shifted in the vertical direction by 2.0 10^{23} cm³ for clarity.